

# GCE

## Electronics

Unit F611: Simple Systems

Advanced Subsidiary GCE

## Mark Scheme for June 2017

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All examiners are instructed that alternative correct answers and unexpected approaches in candidates' scripts must be given marks that fairly reflect the relevant knowledge and skills demonstrated.

Mark schemes should be read in conjunction with the published question papers and the report on the examination.

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### Annotations

1	BOD	31	BOD	Benefit of doubt
2	×	21	Cross	Cross
3	ECF	241	ECF	Error carried forward
4	NBOD	191	NBOD	Benefit of doubt not given
5	~~~	1841	Not Relevant	Expandable vertical wavy line
6	REP	271	REP	Repeat
7	TV	201	τv	Too vague
8	<b>~</b>	11	Tick	Tick
9	0	1741	ZERO	Zero (big)
10				
11				
12				
13				
14				

question	grade		e	expected answe	r		mark	additional guidance
1a	Е	XOR g	ate/EOR gate/	Exclusive-OR	gate		1	
1b								
			Α	В	С			
			0	0	0			
			0	1	1			
			1	0	1			
			1	1	0			
	E	all com	binations of A	and B			1	
	E	C correct					1	
1c	С	$C = A \oplus B$					1	$C = \overline{A} \cdot B + A \cdot \overline{B}$
1d	С	Press b	Press both switches (owtte)					
	С	Leave I	ooth switches	unpressed (owt	te)		1	

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1e	E B D	0 mA for negative voltages For positive voltages: 0 mA then sharp transition with near vertical +ve line after transition (<0.4 V wide by eye) no horizontal line afterwards Transition at 1.9 V	1 1 1	current / mA 15 <sup>4</sup> 10 5 -5 -4 -3 -2 -1 0 1 2 3 4 -5 -10 -15	voltage / V			
1f	E D D	V from logic gate is 5 V R=(5-1.9)/180 17mA	1 1 1	Subtraction				

question	grade	expected answer	mar	additional guidance
			k	
2a	Е	5 x 0.009 = 0.045 W	1	
2b	Е	Lamp glows when switch is pressed	1	
	Е	Because W is 0 V when switch pressed	1	
	D	Output of NAND gate is high when one input low	1	
2c	В	T = 0.5 RC	1	Evidence of choosing correct equation
	Е	$C = \frac{0.5}{0.5 \times 22 \times 10^3} = 4.545 \times 10^{-5}$		Correct calculation using 22 k $\Omega$
	D	C=45 μF	1	Conversion to μF

F611		Mark Schei	ne	June 2	2017
2d	E B A C B C A A	Wark Scher W make digital with one transition at 1 s W = 0 V between 0 s and 1 s X shows charging discharging with bottom>0V top<5V X rising when Y high, X falling when Y low Y square wave (period $\leq$ 1s) Y has period of 0.5 s Z = 5 V between 0 s and 1 s Z is square wave between 1 s and 2.5 s Z is inverse of Y between 1 s and 2.5 s	1 1 1 1 1 1 1 1 1	June 2 Switch switch released $W/V_{0}^{0}$ 0.5 1.5 2.5 tme/s 1.5 2.5 tme/s	2017

question	grade	expected answer	mark	additional guidance
3a	Е	Resistance depends on temperature	1	
	D	Resistance goes down as temperature increases	1	
3b	Е	Correct thermistor symbol	1	No BOD
	D	Forming potential divider with resistor across power	1	Must use correct symbols
		supply and connected to one of comparator inputs		
	D	Potential divider or other voltage reference circuit	1	
	В	Buzzer sounds when thermistor is hot	1	
3c	В	One of:	1	Allow to protect comparator from reverse current from
		So that the buzzer does not sound when output low		(back emf) coil in buzzer.
		To protect buzzer from reversed power connection		Answer must be associated with this application and
				without error
3d	В	13V used as saturated Vout	1	
	А	Subtract 0.7 V to find pd across resistor e.g. (13-0.7)	1	
	С	0.08/(13-0.7) = 0.0065 A No ecf	1	
3e	Е	TB319 ecf from (d)	1	

questio	grad	expected answer	mar	additional	
n	е		k	guidance	
4a	А	3 <sup>rd</sup> expression	1		
4b	А	4 <sup>th</sup> expression	1		
4c	А	4 <sup>th</sup> expression	1		
4d	А	3 <sup>rd</sup> expression	1		

question	grade	expected answer	mar k	additional guidance
5a	В	$Q = \overline{A} \cdot B \cdot \overline{C} + A \cdot B \cdot \overline{C}$	1	Or any equivalent expression e.g. $Q = B \cdot \overline{C}$
5b	А	OR gate at end	1	
	А	Correct logic for first term	1	
	А	Correct logic for second term	1	
				Or any other logically equivalent circuit e.g.
				A
				B 0

question	grade	expected answer	mar	additional guidance
			K	
6a	С	Diode in reverse bias	1	
	В	No current flows through diode	1	
	Α	No current in R <sub>2</sub> so 0 V across R <sub>2</sub>	1	Allow D pulled low by R <sub>2</sub>
6b	С	Evidence of assuming I same through both resistors	1	
	А	Ratio $R_1:R_2 = 1.46:1$	1	7.3:5
	E	Provides 5V at D i.e. correct ratio and $R_1+R_2 > 1 k\Omega$	1	So that current ≤10 mA
6c	E	Use of 4.2 V	1	
	E	I = 4.2/3300 = 1.27 mA ecf	1	Evidence of calculating current in 3.3 k $\Omega$ resistor (or
				ratios)
	С	V across LDR = 15 – 4.2 = 10.8 V ecf	1	Evidence of using voltage across LDR
	С	R = 10.8 / 0.00127 = 8.5 kΩ	1	Mark for correct answer, no ecf
6d	E	LDR resistance goes high	1	
	E	A goes lower than B	1	
	С	So C saturates low (-13 V)	1	
	А	Not gate inverts D to make E high	1	
	A	LED forward bias so LED glows	1	

question	grade	expected answer	mark	additional guidance
7a	С	To show the flow of information	1	
7b	Е	Because the logic gate cannot provide sufficient current	1	
		for the lamp (wtte)		
7ci	Е	Correct MOSFET symbol	1	No errors in symbol
	Е	MOSFET in series with lamp, gate connected to OR gate	1	
	Е	MOSFET D connect to lamp, S connected to 0 V	1	
	E	Correct labels	1	
7cii	D	0.7 x 120k x 150μ	1	Correct calculation
	С	12.6 s	1	Correct conversion to s
7ciii	Е	Lamp shines when switch pressed and	1	
	В	Continues to shine when released	1	Award this mark if total time on >30s
	А	For a total 42.6 s ecf from 7cii for time	1	No ecf if function incorrect (e.g. flashing)
7civ	В	To stop the inputs to the logic gate from floating		
	D	When switch not pressed	1	

question	grade	expected answer					additional guidance
8a	Е	$E = \overline{C}$				1	Accept logically equivalent expressions
	D	$F = A \cdot B$				1	
	D	$G = B + \overline{C}$				1	ecf from E
	С	$H = \overline{(A \cdot B) + (E)}$	$\overline{B} + \overline{\overline{C}}$			1	ecf from F and G
8b	EEEE	1 mark for eac	h correct NAN	D gate equiva	lent	4	
8c	Е						
	E	E	F	G	Н		
	E	1	0	1	0		
	E	0	0	0	1		
		1	0	1	0		
		0	0	1	0		
		1	0	1	0		
		0	0	0	1		
		1	1	1	0		
		0	1	1	0		
		1 mark for eac	h correct colur	nn (ecf H from	n F & G)	4	

#### **Quality of Written Communication**

- 3 The candidate expresses complex ideas extremely clearly and fluently. Sentences and paragraphs follow on from one another smoothly and logically. Arguments are consistently relevant and well structured. There will be few, if any, errors of grammar, punctuation and spelling.
- 2 The candidate expresses straightforward ideas clearly, if not always fluently. Sentences and paragraphs may not always be well connected. Arguments may sometimes stray from the point or be weakly presented. There may be some errors of grammar, punctuation and spelling, but not such as to suggest a weakness in these areas.
- 1 The candidate expresses simple ideas clearly, but may be imprecise and awkward in dealing with complex or subtle concepts. Arguments may be of doubtful relevance or obscurely presented. Errors in grammar, punctuation and spelling may be noticeable and intrusive, suggesting weaknesses in these areas.
- 0 The language has no rewardable features.

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